

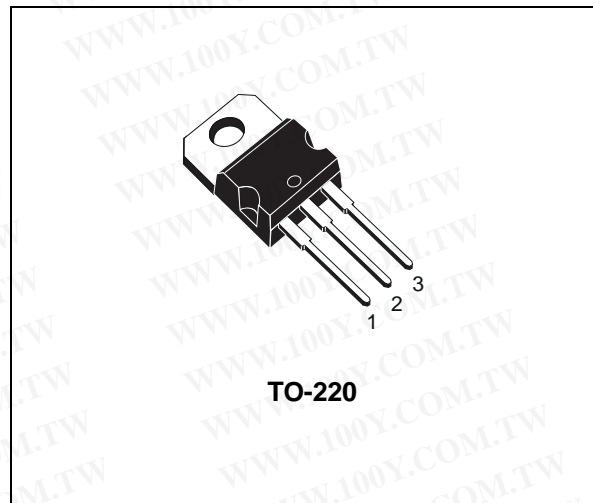


# BDX33B BDX33C BDX34B BDX34C

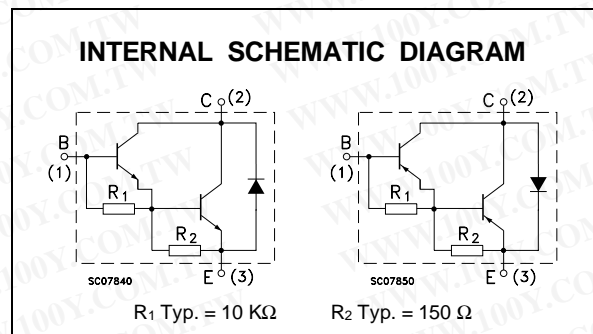
## COMPLEMENTARY SILICON POWER DARLINGTON TRANSISTORS

### DESCRIPTION

The BDX33B and BDX33C are silicon Epitaxial-Base NPN power transistors in monolithic Darlington configuration mounted in Jedec TO-220 plastic package. They are intended for use in power linear and switching applications. The complementary PNP types are BDX34B and BDX34C respectively.



勝特力材料 886-3-5753170  
 勝特力电子(上海) 86-21-34970699  
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### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	NPN	BDX33B	BDX33C	Unit
		PNP	BDX34B	BDX34C	
$V_{CBO}$	Collector-Base Voltage ( $I_E = 0$ )		80	100	V
$V_{CEO}$	Collector-Emitter Voltage ( $I_B = 0$ )		80	100	V
$I_C$	Collector Current		10		A
$I_{CM}$	Collector Peak Current		15		A
$I_B$	Base Current		0.25		A
$P_{tot}$	Total Dissipation at $T_c \leq 25^\circ\text{C}$		70		W
$T_{stg}$	Storage Temperature		-65 to 150		$^\circ\text{C}$
$T_j$	Max. Operating Junction Temperature		150		$^\circ\text{C}$

For PNP types voltage and current values are negative.

# BDX33B BDX33C BDX34B BDX34C

## THERMAL DATA

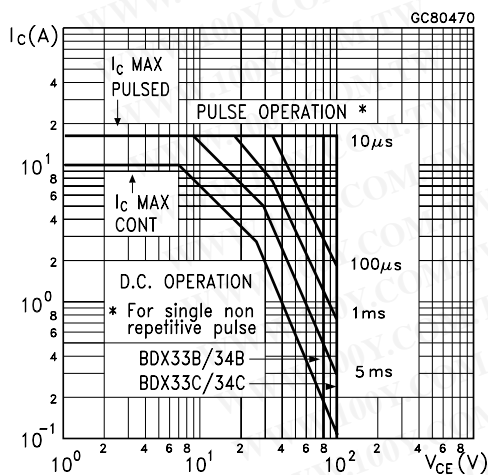
R <sub>thj-case</sub>	Thermal Resistance Junction-case	1.78	°C/W
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## ELECTRICAL CHARACTERISTICS (T<sub>case</sub> = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I <sub>CBO</sub>	Collector Cut-off Current (I <sub>E</sub> = 0)	for <b>BDX33B/34B</b> V <sub>CB</sub> = 80 V for <b>BDX33C/34C</b> V <sub>CB</sub> = 100V T <sub>case</sub> = 100 °C for <b>BDX33B/34B</b> V <sub>CB</sub> = 80 V for <b>BDX33C/34C</b> V <sub>CB</sub> = 100 V			0.2 0.2 5 5	mA mA mA mA
I <sub>CEO</sub>	Collector Cut-off Current (I <sub>B</sub> = 0)	for <b>BDX33B/34B</b> V <sub>CE</sub> = 40 V for <b>BDX33C/34C</b> V <sub>CE</sub> = 50V T <sub>case</sub> = 100 °C for <b>BDX33B/34B</b> V <sub>CE</sub> = 40 V for <b>BDX33C/34C</b> V <sub>CE</sub> = 50 V			0.5 0.5 10 10	mA mA mA mA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V			5	mA
V <sub>CEO(sus)*</sub>	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 100 mA for <b>BDX33B/34B</b> for <b>BDX33C/34C</b>	80 100			V V
V <sub>CER(sus)*</sub>	Collector-emitter Sustaining Voltage (R <sub>BE</sub> = 100 Ω)	I <sub>C</sub> = 100 mA for <b>BDX33B/34B</b> for <b>BDX33C/34C</b>	80 100			V V
V <sub>CEV(sus)*</sub>	Collector-emitter Sustaining Voltage (V <sub>BE</sub> = -1.5 V)	I <sub>C</sub> = 100 mA for <b>BDX33B/34B</b> for <b>BDX33C/34C</b>	80 100			V V
V <sub>CE(sat)*</sub>	Collector-emitter Saturation Voltage	I <sub>C</sub> = 3 A I <sub>B</sub> = 6 mA			2.5	V
V <sub>BE*</sub>	Base-emitter Voltage	I <sub>C</sub> = 3 A V <sub>CE</sub> = 3 V			2.5	V
h <sub>FE*</sub>	DC Current Gain	I <sub>C</sub> = 3 A V <sub>CE</sub> = 3 V	750			V
V <sub>F*</sub>	Parallel-Diode Forward Voltage	I <sub>F</sub> = 8 A			4	V
h <sub>fe</sub>	Small Signal Current Gain	I <sub>C</sub> = 1 A V <sub>CE</sub> = 5 V f = 1MHz	100			

\* Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %  
For PNP types voltage and current values are negative.

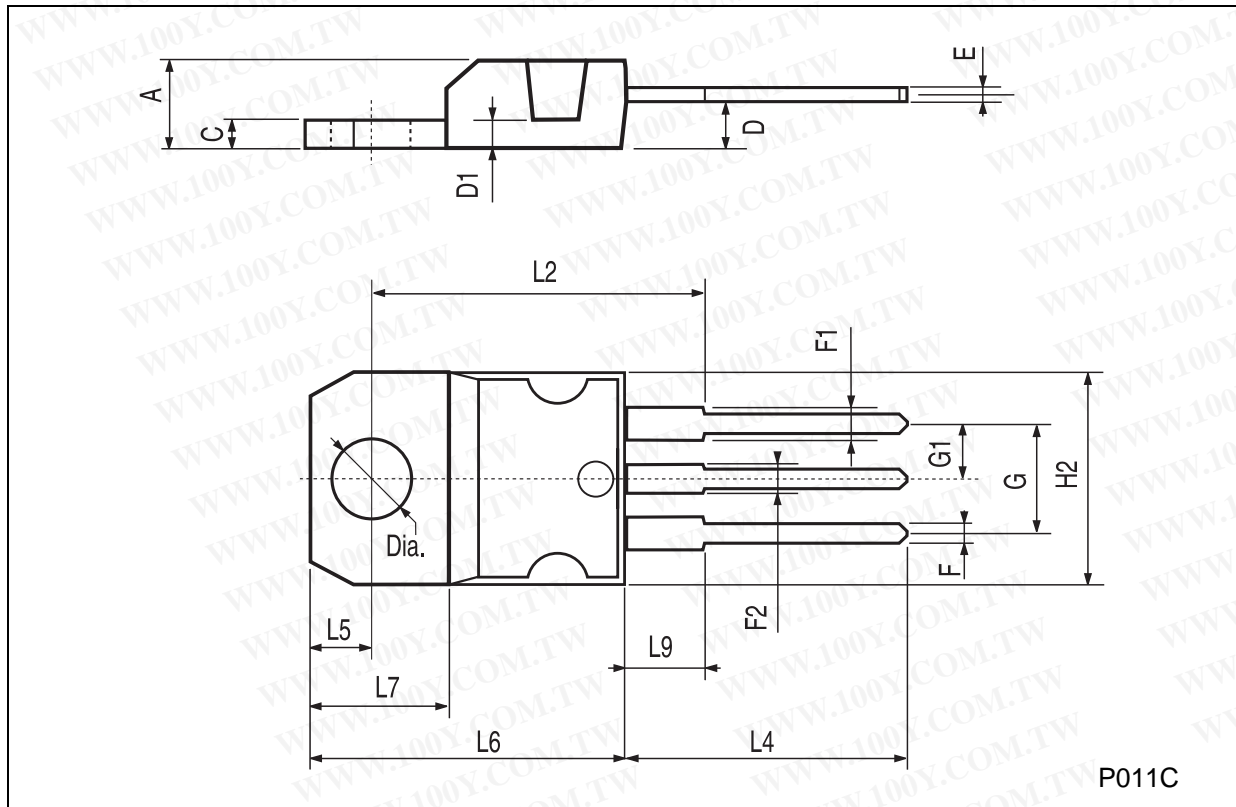
## Safe Operating Area



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**TO-220 MECHANICAL DATA**

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.40		4.60	0.173		0.181
C	1.23		1.32	0.048		0.051
D	2.40		2.72	0.094		0.107
D1		1.27			0.050	
E	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.203
G1	2.4		2.7	0.094		0.106
H2	10.0		10.40	0.393		0.409
L2		16.4			0.645	
L4	13.0		14.0	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.2		6.6	0.244		0.260
L9	3.5		3.93	0.137		0.154
DIA.	3.75		3.85	0.147		0.151



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